

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Revision 1.0: Released to Production

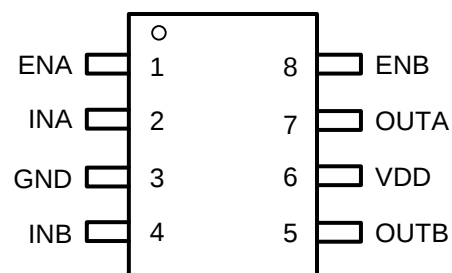
Revision 1.1: Update DEVICE ORDER INFORMATION

ORDERABLE DEVICE	PACKAGING TYPE	STANDARD PACK QTY	PACKAGE MARKING	PINS	PACKAGE DESCRIPTION
SCT52250STDR	Tape & Reel	4000	2250	8	SOP-8L

Over operating free-air temperature unless otherwise noted⁽¹⁾

DESCRIPTION	MIN	MAX	UNIT
ENA, ENB	-0.3	26	V
INA, INB	-5	26	V
OUTA, OUTB	-0.3	VDD+0.3	V
OUTA, OUTB (Pulse<0.2us)	-3	VDD+3	V
VDD	-0.3	26	V
Operating junction temperature T _J ⁽²⁾	-40	150	°C
Storage temperature T _{STG}	-65	150	°C

Top View: SOP-8pin Plastic



- (1) Stresses beyond those listed under Absolute Maximum Rating may cause device permanent damage. The device is not guaranteed to function outside of its Recommended Operation Conditions.
- (2) The IC includes over temperature protection to protect the device during overload conditions. Junction temperature will exceed 150°C when over temperature protection is active. Continuous operation above the specified maximum operating junction temperature will reduce lifetime

NAME	NO.	PIN FUNCTION
ENA	1	Channel A enable logic input, TTL compatible. Floating logic high.
INA	2	Channel A logic input, TTL compatible. Floating logic low.
GND	3	Power ground. Must be soldered directly to ground plane for thermal performance improvement and electrical contact.
INB	4	Channel B logic input, TTL compatible. Floating logic low.
OUTB	5	Channel B gate driver output
VDD	6	Power Supply, must be locally bypassed by the ceramic cap.
OUTA	7	Channel A gate driver output
ENB	8	Channel B enable logic input, TTL compatible. Floating logic high.

Over operating free-air temperature range unless otherwise noted

PARAMETER	DEFINITION	MIN	MAX	UNIT
V _{DD}	Supply voltage range	4.5	24	V
V _{INA,INB}	Input voltage range	-5	24	
T _J	Operating junction temperature	-40	150	°C

PARAMETER	DEFINITION	MIN	MAX	UNIT
V _{ESD}	Human Body Model (HBM), per ANSI-JEDEC-JS-001-2014 specification, all pins ⁽¹⁾	-2	+2	kV
	Charged Device Model (CDM), per ANSI-JEDEC-JS-002-2014 specification, all pins ⁽¹⁾	-0.5	+0.5	kV

(1) HBM and CDM stressing are done in accordance with the ANSI/ESDA/JEDEC JS-001-2014 specification

PARAMETER	THERMAL METRIC	SOP-8L	UNIT
R	Junction to ambient thermal resistance ⁽¹⁾	130	°C/W
R	Junction to case thermal resistance ⁽¹⁾	80	

(1) SCT provides R_{JA} and R_{JC} numbers only as reference to estimate junction temperatures of the devices. R_{JA} and R_{JC} are not a characteristic of package itself, but of many other system level characteristics such as the design and layout of the printed circuit board (PCB) on which the SCT52250 is mounted, and external environmental factors. The PCB board is a heat sink that is soldered to the leads and thermal pad of the SCT52250. Changing the design or configuration of the PCB board changes the efficiency of the heat sink and therefore the actual R_{JA} and R_{JC}.

$V_{IN}=12V$, $T_A= 25^{\circ}C$.

Figure 1. UVLO vs Temperature

Figure 2. Supply current vs Temperature

Figure 3.

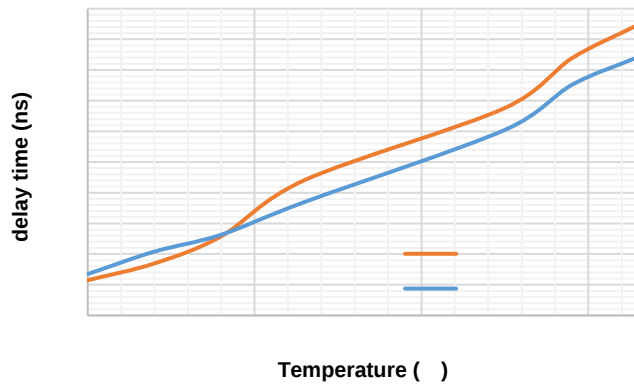


Figure 7. Input to Output Propagation Delay vs Temperature

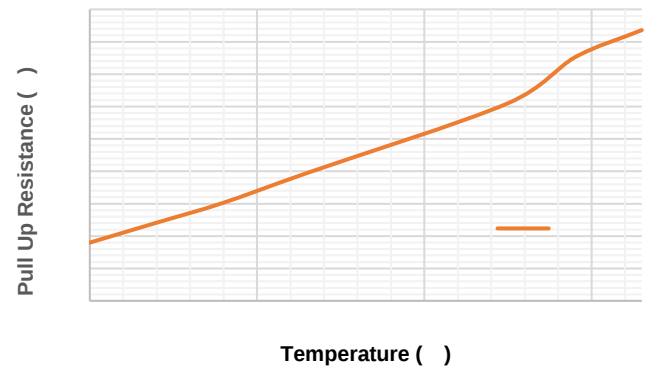


Figure 8. ROH vs Temperature

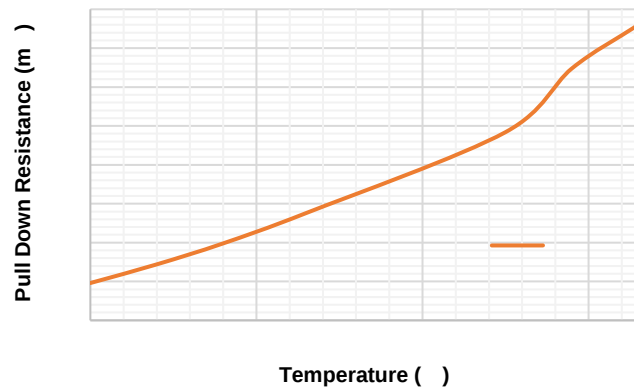


Figure 9. ROL vs Temperature

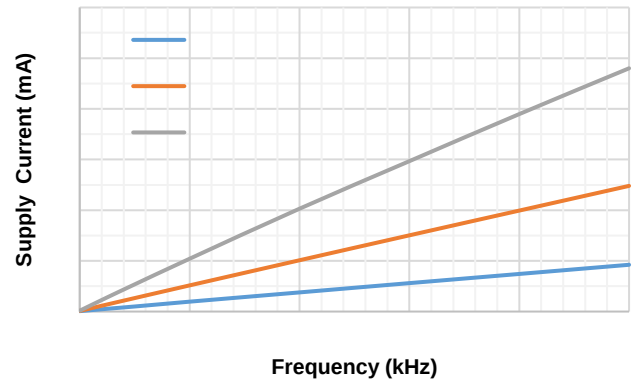
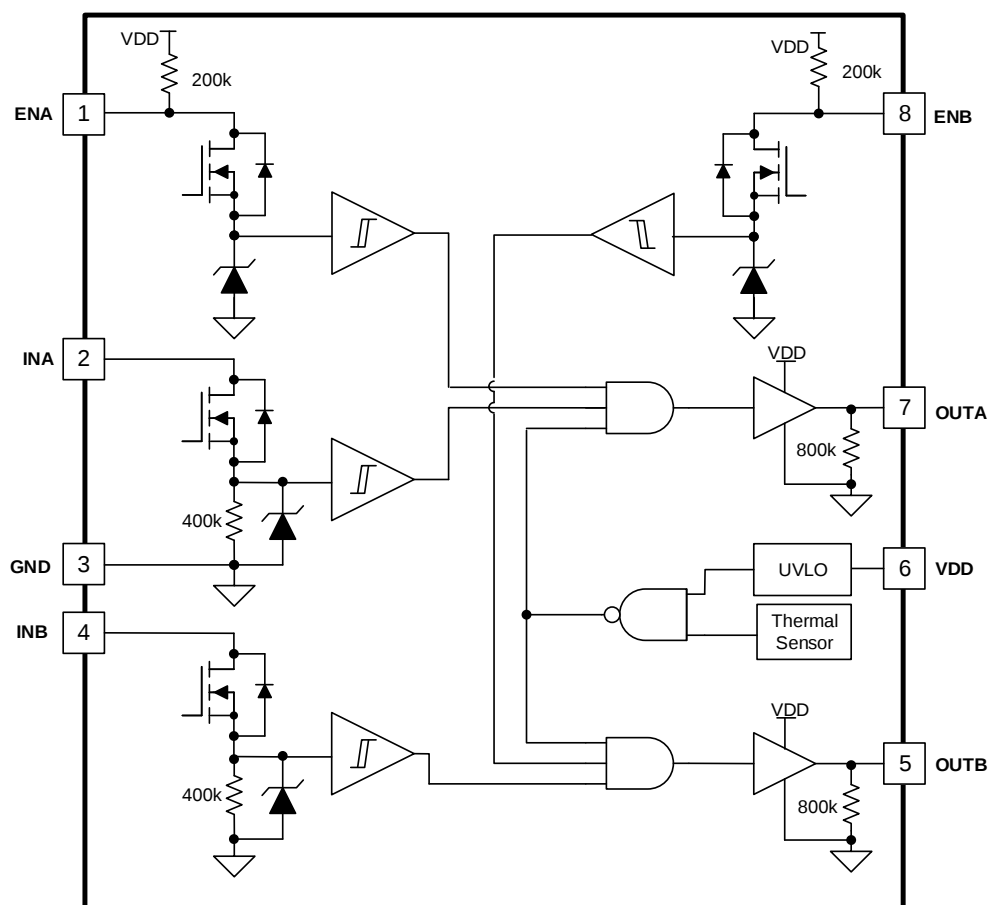


Figure 10. Operation Supply Current vs Frequency(OutA),
C_{OUT}=1.8nF



SCT52250

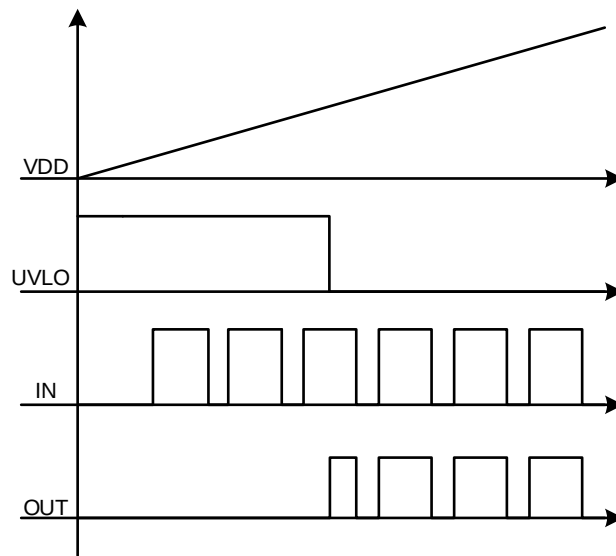
Overview

The SCT52250 is a dual-channel non-invertible high-speed low side driver with supporting up to 24V wide supply for both power MOSFET and IGBT. Each channel can source and sink 5A peak current along with the minimum propagation delay 12ns from input to output. The 1ns delay matching and the stackable output characteristics support higher driving capability demanding in high power converter application. The ability to handle -5V DC input increases the noise immunity of driver input stage, the 24V rail-to-rail output improves the SCT52250 output stage robustness during switching load fast transition. The SCT52250 has flexible input and enable pin configuration, table 1 shows the device output logic truth table.

Table 1: the SCT52250 Device Logic.

ENA	ENB	INA	INB	OUTA	OUTB
H	H	L	L	L	L
H	H	L	H	L	H
H	H	H	L	H	L
H	H	H	H	H	H
L	L	Any	Any	L	L
Any	Any	Floating	Floating	L	L
Floating	Floating	L	L	L	L
Floating	Floating	L	H	L	H
Floating	Floating	H	L	H	L
Floating	Floating	H	H	H	H

VDD Power Supply



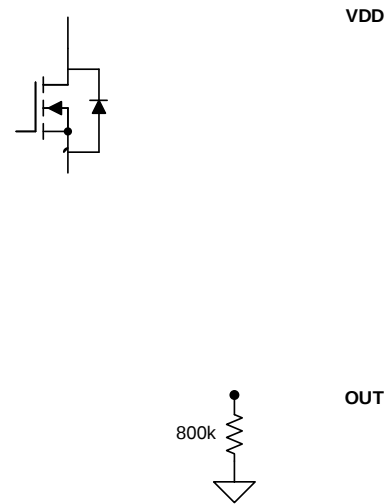


Figure 12. SCT52250 Output Stage

Stackable Output

The SCT52250 features 1ns (typical) delay matching between dual channels, which enables dual channel outputs be stackable when the driven power device required higher driving capability. For example, in a Boost Power Factor Correction converter, there are 2 power MOSFET in parallel to support higher power output capability. The two power MOSFET are preferred to be driven by a common gate control signal. By using SCT52250, the OUTA and OUTB can be connected together to provide the higher driving capability, so does the INA and INB. As a result, a single input signal controls the stacked output combination. To support the stackable output, each channel output stage artificially implements up to 5ns dead-time to avoid the possible shoot-through between two channels as shown Figure 13.

Due to the rising and falling threshold mismatch between INA and INB, cautions must be taken when implementing stackable output of OUTA and OUTB together. The maximum mismatch between INA and INB input threshold is up to 10mV (maximum cross temperature), as a result the allowed minimum slew rate of input logic signal is 2V/us. The following suggestions are recommended when INA and INB connected together and along with the OUTA and OUTB:

1. Apply the fast slew rate dv/dt on input (2 V/us or greater) to avoid

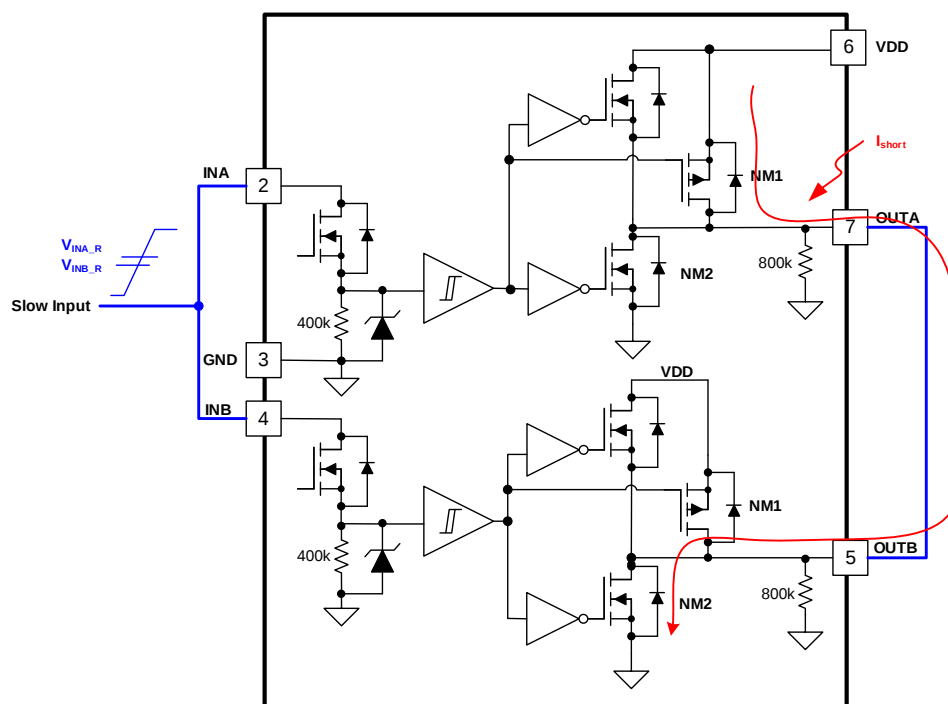


Figure 13. SCT52250 Stackable output

The Figure 14 and Figure 15 shows the stackable output with 2V/us input signal.

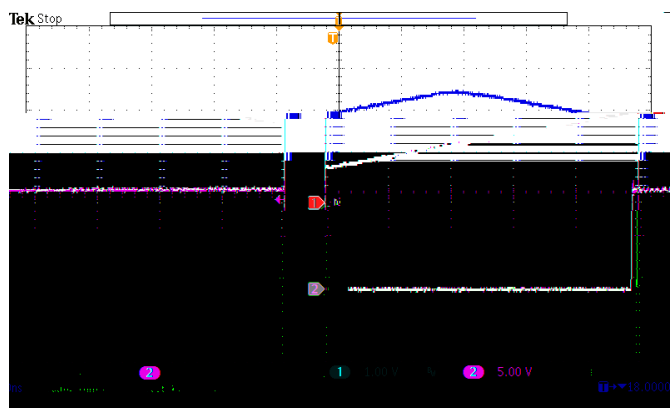


Figure 14. Driver Switching ON

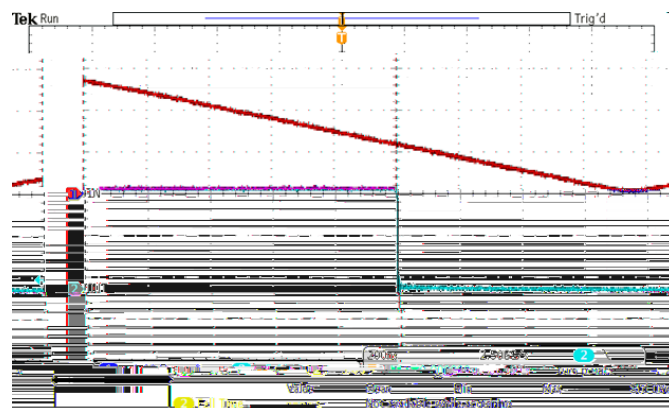


Figure 15. Driver Switching OFF

Thermal Shutdown

Once the junction temperature in the SCT52250 exceeds 162° C, the thermal sensing circuit stops switching until the junction temperature falling below 137° C, and the device restarts. Thermal shutdown prevents the damage on device during excessive heat and power dissipation condition.

Typical Application

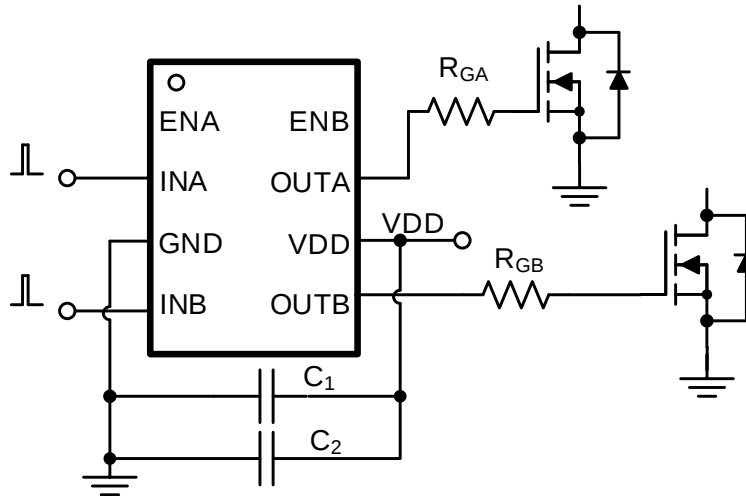


Figure 16. Dual Channel Driver Typical Application

Driver Power Dissipation

Generally, the power dissipated in the SCT52250 depends on the gate charge required of the power device (Q_g), switching frequency, and use of external gate resistors. The SCT52250 features very low quiescent currents and internal logic to eliminate any shoot-through in the output driver stage, their effect on the power dissipation within the gate driver is negligible.

For the pure capacitive load, the power loss of each channel in SCT52250 is:

(1)

Where

- V_{DD} is supply voltage
- C_{Load} is the output capacitance
- f_{SW} is the switching frequency

For the the switching load of power MOSFET, the power loss of each channel in the SCT52250 is shown in equation (2), where charging a capacitor is determined by using the equivalence $Q_g = C_{LOAD}V_{DD}$. The gate charge includes the effects of the input capacitance plus the added charge needed to swing the drain voltage of the power device as it switches between the ON and OFF states. Manufacturers provide specifications that provide the typical and maximum gate charge, in nC, to switch the device under specified conditions.

(2)

Where

- Q_g is the gate charge of the power device
- f_{SW} is the switching frequency
- V_{DD} is the supply voltage

If R_G applied between driver and gate of power device to slow down the power device transition, the power dissipation of the driver shows as below:

$$P_{Diss} = \frac{1}{2} \left(\frac{V_{DD}^2}{R_G} \right) f_{SW}$$

(3)

Where

- R_{OH} is the equivalent pull up resistance of SCT52250
- R_{OL} is the pull down resistance of SCT52250
- R_G is the gate resistance between driver output and gate of power device.

Application Waveforms

VDD=12V unless otherwise noted

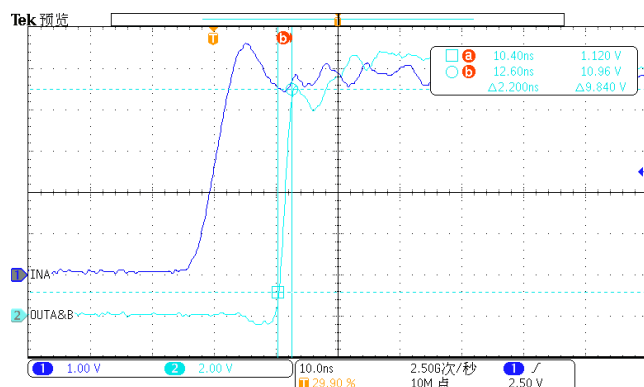


Figure 17. Driver Switching ON (Out capacitance=0nF)

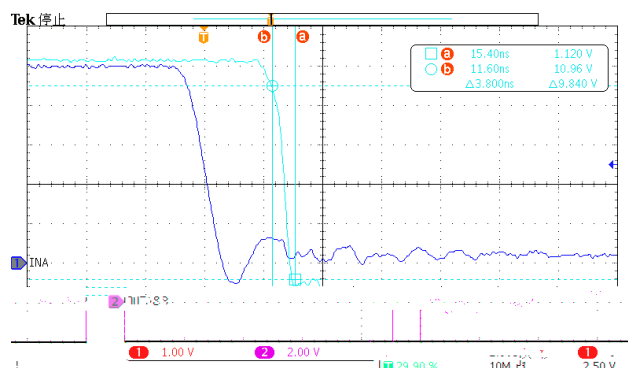


Figure 18. Driver Switching OFF (Out capacitance=0nF)

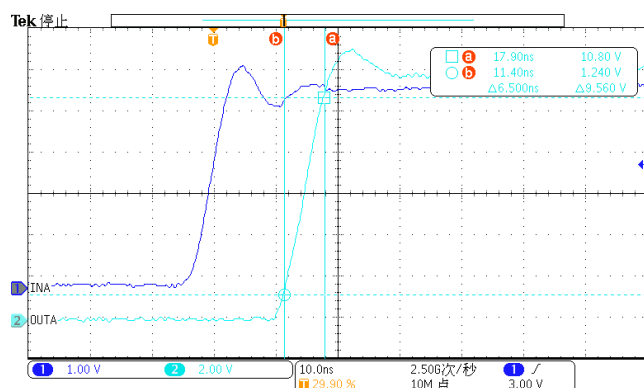


Figure 19. Driver Switching ON (Out capacitance=1.8nF)

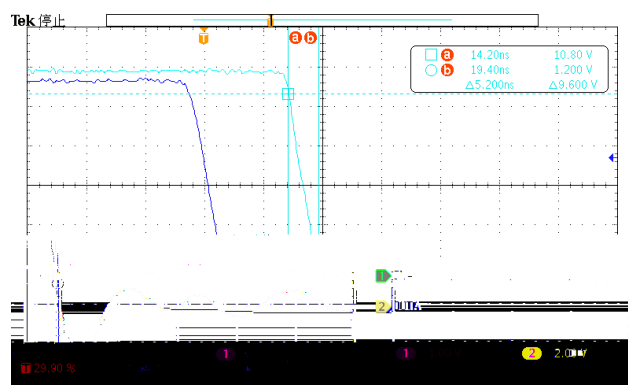


Figure 20. Driver Switching OFF (Out capacitance=1.8nF)

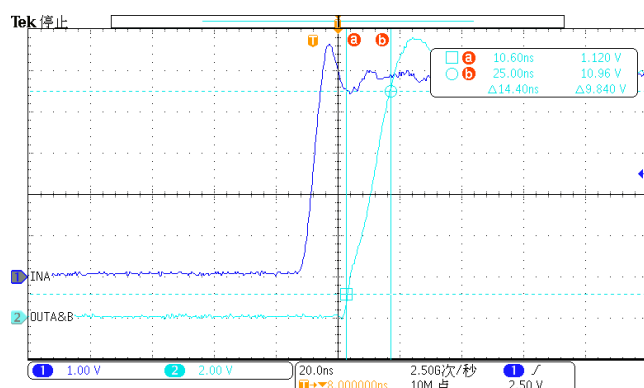


Figure 21. Driver Switching ON (Out capacitance=3.3nF)

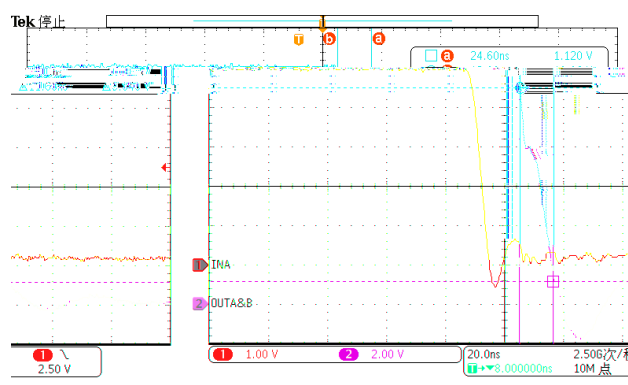


Figure 22. Driver Switching OFF (Out capacitance=3.3nF)

Application Waveforms

VDD=12V unless otherwise noted

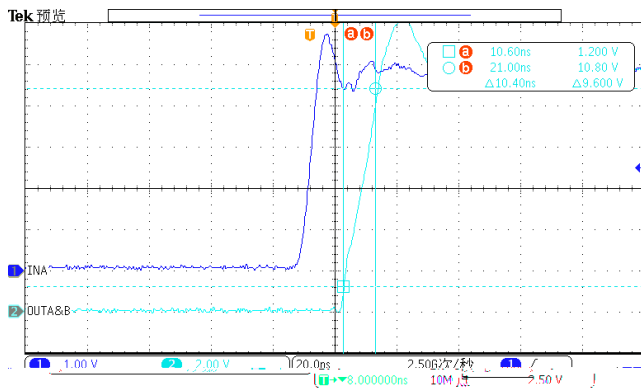


Figure 23. Stackable Output Rise (Out capacitance=3.3nF)

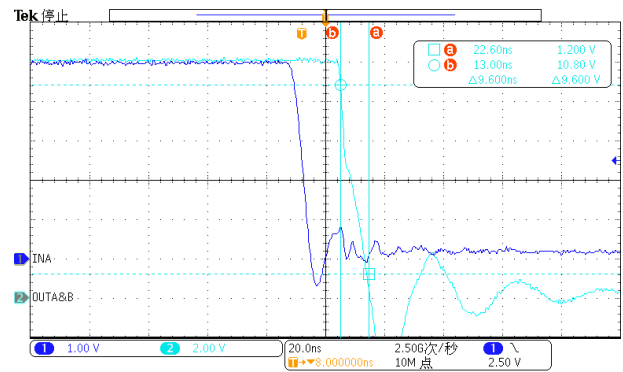


Figure 24. Stackable Output Fail (Out capacitance=3.3nF)

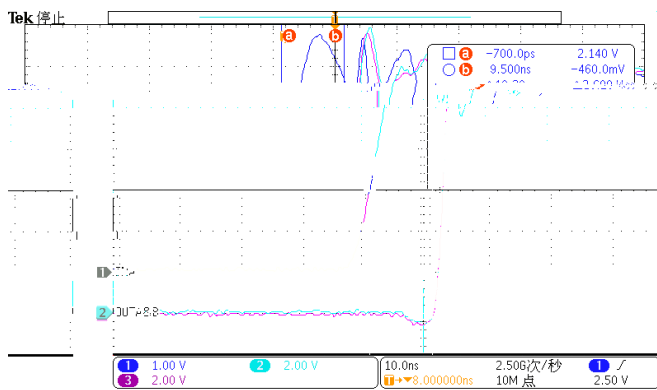


Figure 25. Delay Matching Rise (Out capacitance=1.8nF)

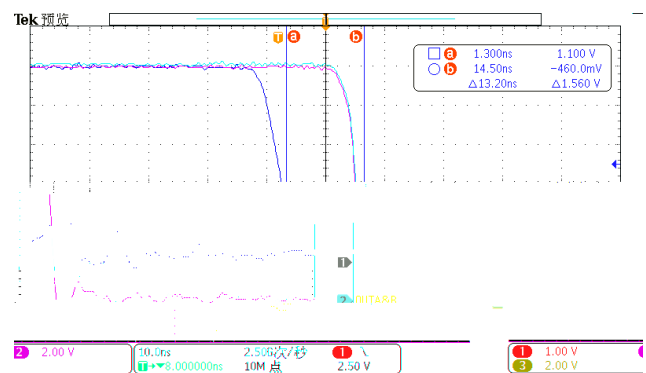


Figure 26. Delay Matching Fail (Out capacitance=1.8nF)

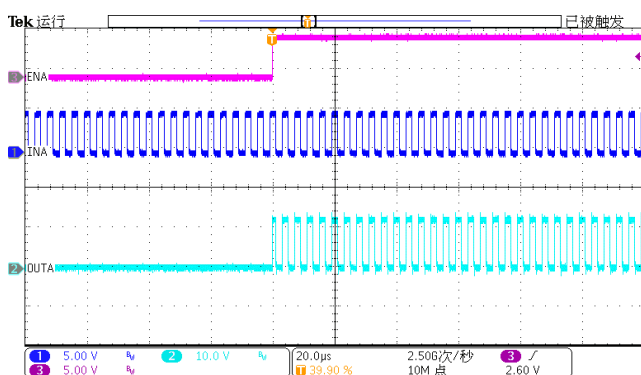


Figure 27. Enable

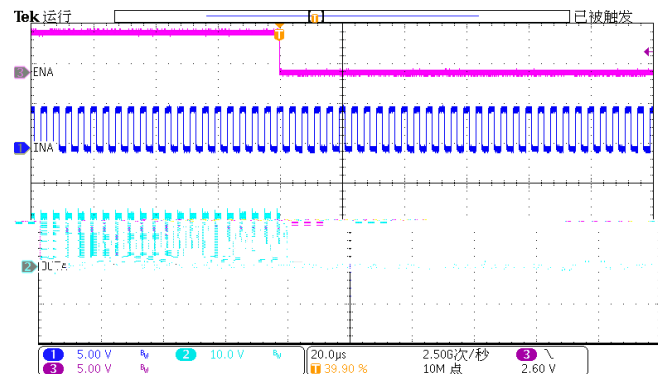


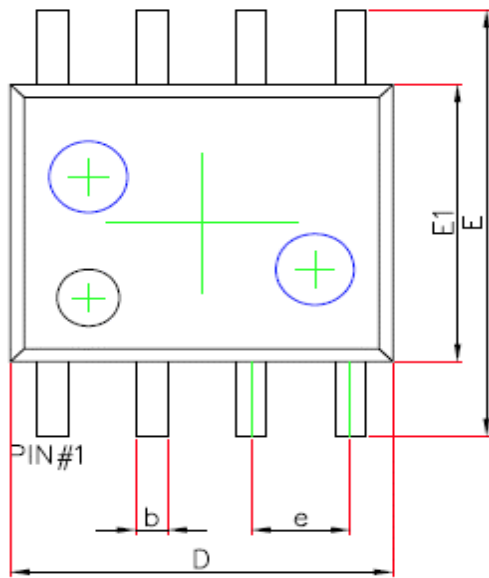
Figure 28. Disable

SCT52250

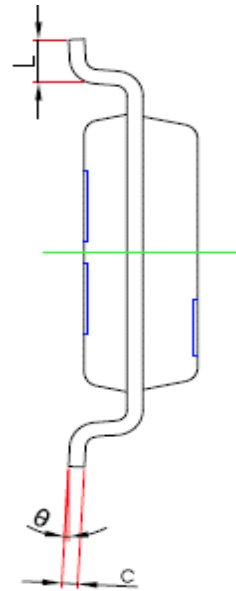
Layout Guideline

The SCT52250 provides the 5A output driving current and features very short rising and falling time at the power devices gate. The high di/dt causes driver output unexpected ringing when the driver output loop is not designed well. The regulator could suffer from malfunction and EMI noise problems if the power device gate has serious ringing. Below are the layout recommendations with using SCT52250 and Figure 23 is the layout example.

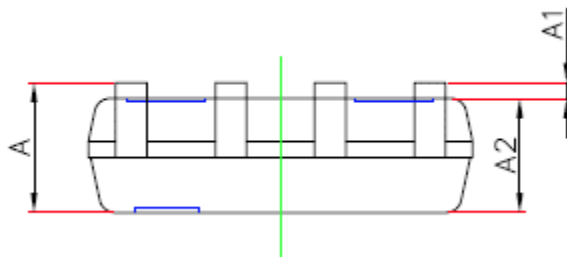
Put the SCT52250 as close as possible to the power device to minimize the gate driving loop including the driver output and power device gate. The power supply decoupling capacitors needs to be close to the VDD pin and G-45(-46Fn TJET



TOP VIEW



BOTTOM VIEW



SIDE VIEW

NOTE:

1. Drawing proposed to be made a JEDEC package outline MO-220 variation.
2. Drawing not to scale.
3. All linear dimensions are in millimeters.
4. Thermal pad shall be soldered on the board.
5. Dimensions of exposed pad on bottom of package do not include mold flash.
6. Contact PCB board fabrication for minimum solder mask web tolerances between the pins.

SYMBOL	Unit: Millimeter		
	MIN	TYP	MAX
A	1.45	---	1.75
A1	0.1	---	0.25
A2	1.35	---	1.55
b	0.33	---	0.51
c	0.17	---	0.25
D	4.7		5.1
E	5.8		6.2
E1	3.8		4.0
e	1.27BSC		
L	0.4		1.27
	0°		8°

